

### 山东晶导微电子股份有限公司 Jingdao Microelectronics co LTD MR

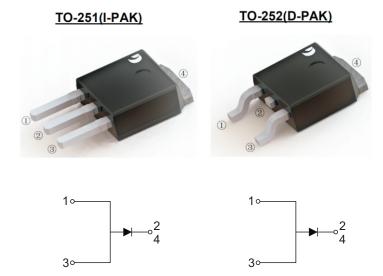
## Jingdao Microelectronics co.LTD MBR840xS THRU MBR8200xS

### **SCHOTTKY BARRIER RECTIFIERS**

Reverse Voltage - 40 to 200 V Forward Current - 8.0 A

#### **FEATURES**

- High current capability
- Low forward voltage drop
- · Low power loss, high efficiency
- High surge capability
- · High temperature soldering guaranteed
- Mounting position: any



# MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS Ratings at 25°C ambient temperature unless otherwise specified

CHARACTERISTICS	TO-251	MBR840VS	MBR845VS	MBR860VS	MBR8100VS	MBR8150VS	MBR8200VS	Units				
CHARACTERISTICS	TO-252	MBR840DS	MBR845DS	MBR860DS	MBR8100DS	MBR8150DS	MBR8200DS	Onits				
Maximum Recurrent Peak Reverse Voltage	$V_{RRM}$	40	45	60	100	150	200	V				
Maximum RMS voltage	V <sub>RMS</sub>	28	31.5	42	70	105	140	V				
Maximum DC Blocking Voltage	V <sub>DC</sub>	40	45	60	100	150	200	V				
Maximum Average Forward Rectified Current	I <sub>F(AV)</sub>		8.0									
Peak Forward Surge Current,8.3ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I <sub>FSM</sub>	I <sub>FSM</sub> 150										
Max Instantaneous Forward Voltage at 8 A	V <sub>F</sub>	0.	65	0.70	0.85 0.90		0.92	V				
Maximum DC Reverse Current T <sub>a</sub> = 25°C at Rated DC Reverse Voltage T <sub>a</sub> =125°C	I <sub>R</sub>	I <sub>R</sub> 0.1 0.05 20										
Typical Junction Capacitance (1)	Junction Capacitance (1) C <sub>j</sub> 600 400											
Typical Thermal Resistance (2)	$R_{\theta JA}$	. 35										
Operating Junction Temperature Range	Tj	-55 ~ +150           -55 ~ +175										
Storage Temperature Range	$T_{stg}$	-55 ~ +150           -55 ~ +175										

<sup>(1)</sup> Measured at 1 MHz and applied reverse voltage of 4 V D.C

<sup>(2)</sup> P.C.B. mounted with 10cmX10cmX1mm copper pad areas.

Fig.1 TYPICAL FORWARD CURRENT DERATING CURVE

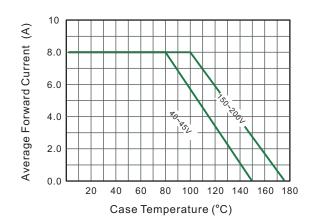


Fig.2 Typical Reverse Characteristics

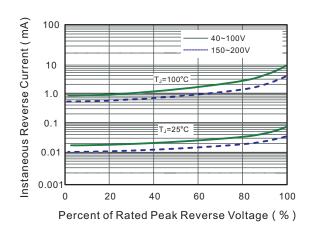


Fig.3 Typical Forward Characteristic

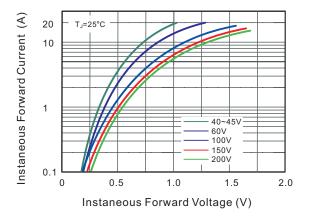


Fig.4 Typical Junction Capacitance

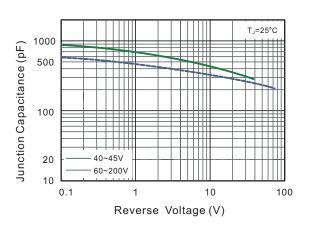


Fig.5 Maximum Non-Repetitive Peak Forward Surage Current

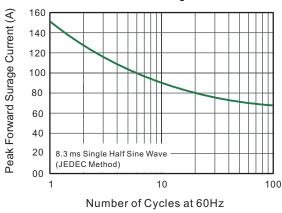
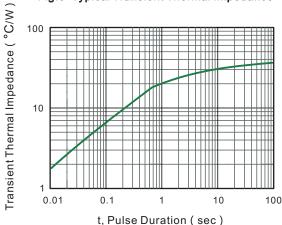
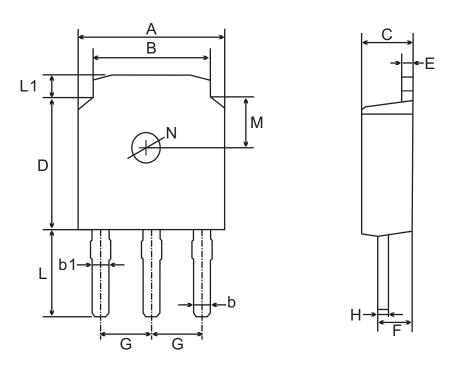


Fig.6- Typical Transient Thermal Impedance



### TO-251(D-PAK) Package Outline Dimensions



TO-251(I-PAK) mechanical data

UN	NIT.	Α	В	b	b1	С	D	E	F	G	Н	L	L1	М	N
mm	max	6.7	5.5	0.8	0.9	2.5	6.3	0.6	1.8	2.29	0.55	4.3	1.2	1.8	1.3 TYPICAL
mm	min	6.3	5.1	0.3	0.76	2.1	5.9	0.4	1.3	TYPICAL	0.45	3.9	0.8	TYPICAL	
mil	max	264	217	31	35	98	248	24	71	90	22	169	47	71	51
mil	min	248	201	12	30	83	232	16	51	TYPICAL	18	154	31	TYPICAL	TYPICAL

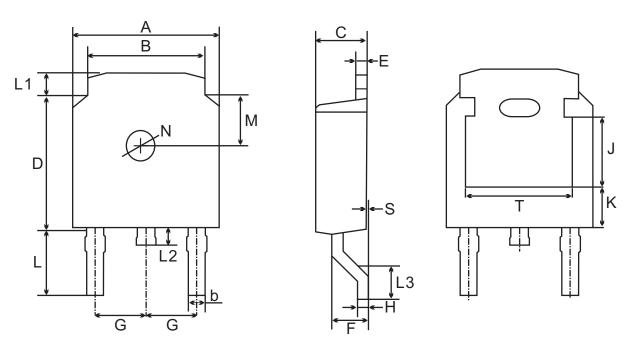
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## TO-252(D-PAK) Package Outline Dimensions



TO-252(D-PAK) mechanical data

UN	VIT.	Α	В	b	С	D	Е	F	G	Н	L	L1	L2	L3	S	М	N	J	K	Т
	max	6.7	5.5	0.8	2.5	6.3	0.6	1.8	2.29	0.55	3.1	1.2	1.0	1.75	0.1	1.0		3.16 ref.		4.83
mm	min	6.3	5.1	0.3	2.1	5.9	0.4	1.3	TYPICAL	0.45	2.7	0.8	0.6	1.40	0.0					ref.
	max	264	217	31	98	248	24	71	90	22	122	47	39	69	4	71	51	124	71	190
mil -	min	248	201	12	83	232	16	51	TYPICAL	18	106	31	24	55	0	TYPICAL	TYPICAL	ref.	ref.	ref.

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